

**Degradation of 600-V 4H-SiC Schottky diodes under irradiation with 0.9 MeV electrons**

Lebedev, Alexander A.; Davidovskaja, Klavdia; Kozlovski, Vitali V.; **Korolkov, Oleg; Sleptšuk, Natalja; Toompuu, Jana** Silicon Carbide and Related Materials 2016 : selected, peer reviewed papers from the 11th European Conference on Silicon Carbide and Related Materials 2016 (ECSCRM 2016), September 25-29, 2016, Halkidiki, Greece 2017 / p. 447-450 : ill  
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**Surface structure transformation in double forged tungsten upon single and sequenced irradiation using different types of radiation facilities**

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